

Voltage-Controlled Attenuator Module 100 to 2000 MHz

Rev. V3

Features

- FAST SWITCHING: < 0.2 μsec, 10 TO 90% (TYP.)
 < 1 μsec, 0 TO 100% (TYP.)
- HIGH DYNAMIC RANGE: 40 dB TO 1000 MHz (TYP.)
- LOW VSWR: 1.4:1 (TYP.)

Description

The G30 attenuator is a discrete hybrid design, which uses thin film manufacturing processes for accurate performance and high reliability.

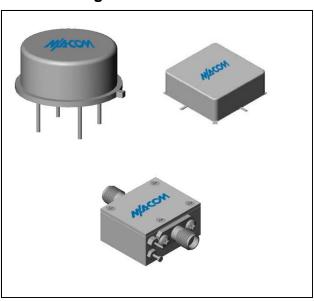
This design uses three pin diodes to provide a non linear attenuation response across a broadband frequency range. Both TO-8 and Surface Mount packages are hermetically sealed, and MIL-STD-883 environmental screening is available.

Ordering Information

| Part Number | Package | |
|-------------|-------------------|--|
| G30 | TO-8 | |
| SMG30 | Surface Mount | |
| CG30 ** | SMA Connectorized | |

^{**} The connectorized version is not RoHs compliant.

Product Image



Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +15 V_{DC}$

| Parameter | 11 | Typical | Guaranteed | |
|---|----------------|----------------------|-------------------|-------------------|
| | Units | 25°C | 0º to 50°C | -54º to +85ºC* |
| Frequency | MHz | 5-2200 | 100-2000 | 100-2000 |
| Maximum Attenuation Available (min) 100-500 MHz 500-1000 MHz 1000-2000 MHz | dB dB dB | >50 >44 >38 | 40 35 30 | 37 32 27 |
| Insertion Loss (Vctrl = +15 V) (max) 100-500 MHz 500-1000 MHz 1000-2000 MHz | dB dB dB | <2.1 <2.3 <3.0 | 2.8 3.0 3.5 | 3.0 3.2 3.8 |
| VSWR (worst case in attenuation range) 0-25 dB Attenuation >25 dB Attenuation | dB dB | 1.4:1 <1.7:1 | 2.0:1 2.2:1 | 2.0:1 2.2:1 |
| Flatness Over Frequency (max) (Attenuation = min to 15 dB, 100-1000 MHz) 100-1000 MHz 1000-2000 MHz | dB dB | ±0.5 ±1.0 | ±1.0 ±1.5 | ±1.0 ±1.7 |
| Switching Speed (max.) 10% - 90% 0% - 100% | µsec µsec | <0.2 <1 | 0.4 2 | 0.6 3 |
| Bias Voltage | Volts | +15 | +15 | +15 |
| Bias Current (max) | mA | 7 | 10 | 12 |
| Control Voltage | Volts | 0 to +15 | 0 to +15 | 0 to +15 |
| Control Current (max) | mA | 7 | 10 | 10 |

^{*}Over temperature performance limits for part number CG30, guaranteed from 0°C to +50°C only.

- North America Tel: 800.366.2266 Europe Tel: +353.21.244.6400
- India Tel: +91.80.4155721 China Tel: +86.21.2407.1588

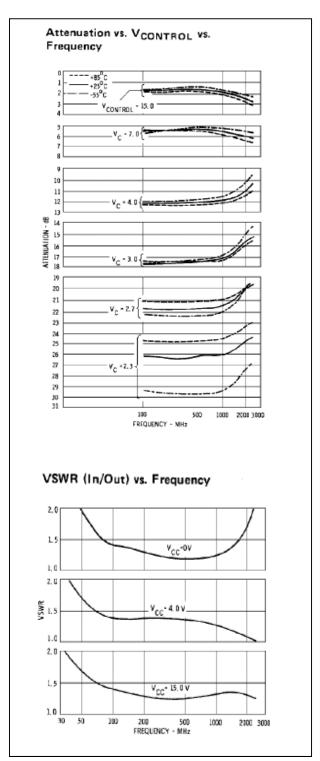
 Visit www.macomtech.com for additional data sheets and product information.

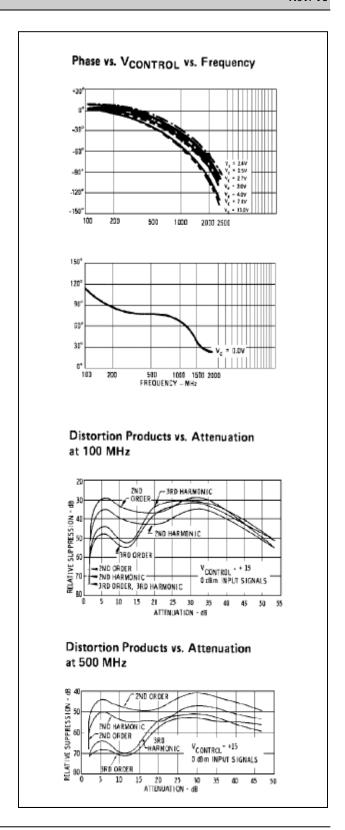


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Typical Performance Curves at +25°C





Commitment to produce in volume is not guaranteed.

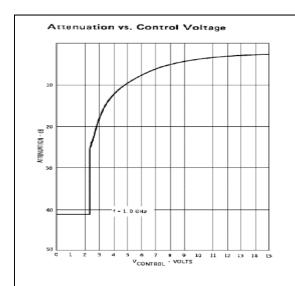
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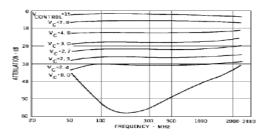
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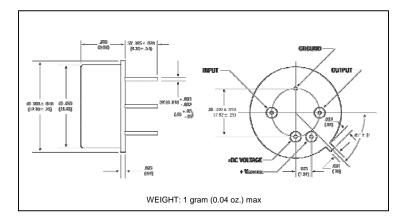
Attenuation vs. V_{CONTROL} vs.



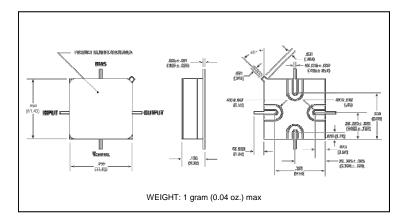
Absolute Maximum Ratings

| Parameter | Absolute Maxi- mum | |
|---|-----------------------|--|
| Storage Temperature | -62°C to +125°C | |
| Maximum Case Temperature | 125ºC | |
| Maximum DC Voltage | +18 V | |
| Maximum DC Bias Voltage | +20 V | |
| Maximum Short Term RF Input power (1 minute max.) | 200 mW | |
| Maximum Peak Power (3 µsec max.) | 1 W | |
| "S" Series Burn-In Temperature (case) | +125°C | |

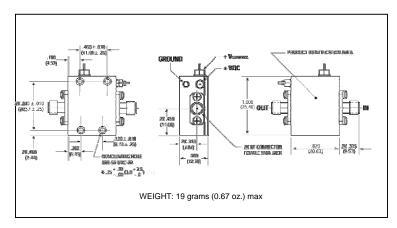
Outline Drawing: TO-8 *



Outline Drawing: Surface Mount



Outline Drawing: SMA Connectorized



- * Dimensions are inches (millimeters) ±0.015 (0.38) unless otherwise specified.
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